

EPO-TEK<sup>®</sup> H21D

**Technical Data Sheet** 

For Reference Only

Electrically Conductive, Silver Epoxy

**Recommended Cure:** 

## 150°C / 1 Hour

Rev: VI		
No. of Components:	Two	
Mix Ratio by Weight:	10 : 1	
Specific Gravity:	Part A: 2.45 Part B	: 2.14
Pot Life:	15 Horus	
Shelf Life:	One year at room temperature	

Minimum Alternative Cure(s): may not achieve performance properties below 150°C / 5 Minutes 120°C / 15 Minutes 80°C / 90 Minutes

NOTE: Container(s) should be kept closed when not in use. Filled systems should be stirred thoroughly before mixing and prior to use. Please see Applications Note on our website.

**<u>Product Description</u>**: EPO-TEK<sup>®</sup> H21D is a two component, high Tg, silver-filled epoxy designed for chip bonding in microelectronic and optoelectronic applications.

## **Typical Properties:**

Date: Apr 2014

To be used as a guide only, not as a specification. Different batches, conditions & applications yield differing results. Cure condition: 150°C/1 hour \* denotes test on lot acceptance basis Data below is not guaranteed.

PHYSCIAL PROPERTIES	S:
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* Color (before cure):	Part A: Silver Part B: Silver		
* Consistency	Smooth paste		
* Viscosity (23°C): @ 20 rpm	14,000-20,400 <b>cPs</b>		
Thixotropic Index:	2.6		
* Glass Transition Temp:	≥ 100 °C (Dynamic Cure:20-200°C/ISO 25 Min; Ramp -10-200°C @ 20°C/Min)		
Coefficient of Thermal Expansion (CTE):			
Below Tg:	42 x 10 <sup>-6</sup> in/in°C		
Above Tg:	225 x 10 <sup>-6</sup> in/in°C		
Shore D Hardness:	60		
Lap Shear @ 23°C:	1,504 <b>psi</b>		
Die Shear @ 23°C:	≥ 10 <b>Kg</b> 3,400 <b>psi</b>		
Degradation Temp:	416 ° <b>C</b>		
Weight Loss: @ 200°C	0.03 %		
@ 250°C	0.06 %		
@ 300°C	0.17 %		
OperatingTemp: : Continuous	s: - 55° <b>C to</b> 250° <b>C</b>		
Intermitten	t: - 55° <b>C to</b> 350° <b>C</b>		
Storage Modulus:	802,491 <b>psi</b>		
Ion Content: C	l: 64 ppm		
NA	*: 72 ppm		
NH₄	*: 121 <b>ppm</b>		
* Particle Size:	≤ 45 microns		
ELECTRICAL AND THERMAL PROPERTIES:			
Thermal Conductivity:	1.0 <b>W/mK</b>		
* Volume Resistivity @ 23°C:	≤ 0.0009 <b>Ohm-cm</b>		

Epoxies and Adhesives for Demanding Applications™

This information is based on data and tests believed to be accurate. Epoxy Technology, Inc. makes no warranties (expressed or implied) as to its accuracy and assumes no liability in connection with any use of this product.

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## **EPO-TEK<sup>®</sup> H21D Advantages & Suggested Application Notes:**

- Extended pot-life and can be cured at relatively low temperatures such as 80°C.
- Designed to be used in the 300°C range for applications such as wire bonding operations and eutectic lid-sealing processes.
- Contains no solvents or thinners. NASA approved, low outgassing epoxy <u>http://outgassing.nasa.gov/</u>
- Also suggested for hybrid aerospace circuits found in Rf / Microwave devices like cockpits and satellites.
- Paste-like rheology allows for application by commercial dispensing equipment, stamping, screen printing, or by hand with spatula or toothpick.
- Compatible with Au-plated ceramic substrates found in traditional and custom hybrids.

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